CA158, CA158A, CA258, CA358, CA358A, CA2904, LM358, LM2904

OBSOLETE PRODUCT UBOULE IE PRUDUUI NO RECOMMENDED REPLACEMENT Data Sheet

May 2001 File Number 1019.7

Dual, 1MHz, Operational Amplifiers for Commercial Industrial, and Military Applications

interc

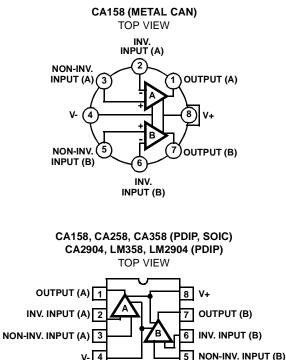
The CA158, CA158A, CA258, CA358, CA358A and CA2904 types consist of two independent, high gain, internally frequency compensated operational amplifiers which are designed specifically to operate from a single power supply over a wide range of voltages. They may also be operated from split power supplies. The supply current is basically independent of the supply voltage over the recommended voltage range.

These devices are particularly useful in interface circuits with digital systems and can be operated from the single common 5VDC power supply. They are also intended for transducer amplifiers, DC gain blocks and many other conventional op amp circuits which can benefit from the single power supply capability.

The CA158, CA158A, CA258, CA358, CA358A, and CA2904 types are an equivalent to or a replacement for the industry types 158, 158A, 258, 258A, 358, 358A, and CA2904.

Technical Data on LM Branded types is identical to the corresponding CA Branded types.

Pinouts



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Features

- Internal Frequency Compensation for Unity Gain
- High DC Voltage Gain 100dB (Typ)
- Wide Bandwidth at Unity Gain1MHz (Typ)
- Wide Power Supply Range:
- Single Supply 3V to 30V
- Dual Supplies..... ±1.5V to ±15V
- Low Input Bias Current
- Low Input Offset Voltage and Current
- Input Common-Mode Voltage Range Includes Ground
- Differential Input Voltage Range Equal to V+ Range
- Large Output Voltage Swing 0V to V+ -1.5V

Related Literature

 TB363, Guidelines for Handling and Processing Moisture Sensitive Surface Mount Devices (SMDs)

Part Number Information

PART NUMBER	TEMP. RANGE (^o C)	PACKAGE	PKG. NO.
CA0158E	-55 to 125	8 Ld PDIP	E8.3
CA0158AE	-55 to 125	8 Ld PDIP	E8.3
CA0158M	-55 to 125	8 Ld SOIC	M8.15
CA0158T	-55 to 125	8 Pin Can	T8.C
CA0258E	-25 to 85	8 Ld PDIP	E8.3
CA0258M	-25 to 85	8 Ld SOIC	M8.15
CA0358E	0 to 70	8 Ld PDIP	E8.3
CA0358AE	0 to 70	8 Ld PDIP	E8.3
CA0358M	0 to 70	8 Ld SOIC	M8.15
CA2904E	-40 to 85	8 Ld PDIP	E8.3
LM358N	0 to 70	8 Ld PDIP	E8.3
LM2904N	-40 to 85	8 Ld PDIP	E8.3

Absolute Maximum Ratings

Supply Voltage	
CA2904, LM2904	26V or ±13V
Other Types	32V or ±16V
Differential Input Voltage (All Types)	32V
Input Voltage	0.3V to V+
Input Current (V _I < -0.3V, Note 1)	50mA
Output Short Circuit Duration (V+ \leq 15V, Note 2)	Continuous

Operating Conditions

Temperature Range	
CA158, CA158A	
CA258,	
CA2904, LM2904	
CA358, CA358A, LM358	

Thermal Information

Thermal Resistance (Typical, Note 3)	θ _{JA} (^o C/W)	θ _{JC} (^o C/W)
PDIP Package	130	N/A
SOIC Package	170	N/A
Can Package	155	67
Maximum Junction Temperature (Can Pac	kage)	175 ⁰ C
Maximum Junction Temperature (Plastic P	ackage)	150 ⁰ C
Maximum Storage Temperature Range		5°C to 150°C
Maximum Lead Temperature (Soldering 10	Ds)	300 ⁰ C
(SOIC - Lead Tips Only)		

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTES:

- 1. This input current will only exist when the voltage at any of the input leads is driven negative. This current is due to the collector base junction of the input PNP transistors becoming forward biased and thereby acting as input diode clamps. In addition to this diode action, there is also lateral NPN parasitic transistor action on the IC chip. This transistor action can cause the output voltages of the amplifiers to go to the V+ voltage level (or to ground for a large overdrive) for the time duration that an input is driven negative. This transistor action is not destructive and normal output states will re-establish when the input voltage, which was negative, again returns to a value greater than -0.3V.
- The maximum output current is approximately 40mA independent of the magnitude of V+. Continuous short circuits at V+ > 15V can cause excessive power dissipation and eventual destruction. Short circuits from the output to V+ can cause overheating and eventual destruction of the device. Destructive dissipation can result from simultaneous short circuits on both amplifiers.
- 3. θ_{JA} is measured with the component mounted on an evaluation PC board in free air.

		ТЕМР		CA158A					
PARAMETER	TEST CONDITIONS	(°C)	MIN	ТҮР	MAX	MIN	TYP	MAX	UNITS
Input Offset		25	-	1	2	-	2	3	mV
Voltage (Note 6)		Full	-	-	4	-	-	5	mV
Average Input Offset Voltage Drift	$R_{S} = 0\Omega$	Full	-	7	15	-	7	20	μV/ ^o C
Input Common Mode Voltage Range (Note 5)	V+ = 30V	25	0	-	V+ -1.5	0	-	V+ -1.5	V
	V+ = 30V	Full	0	-	V+ -2	0	-	V+ -2	V
Common Mode Rejection Ratio	DC	25	70	85	-	65	85	-	dB
Power Supply Rejection Ratio	DC	25	65	100	-	65	100	-	dB
Input Bias	lı+ or lı-	25	-	20	50	-	45	100	nA
Current (Note 4)	lı+ or lı-	Full	-	40	100	-	40	200	nA
Input Offset	lı+ - lı-	25	-	2	10	-	5	30	nA
Current	lı+ - lı-	Full	-	-	30	-	-	75	nA
Average Input Offset Current Drift		Full	-	10	200	-	10	300	pA/ ^o C
Large Signal Voltage Gain	$R_L \ge 2k\Omega$, V+ = 15V (For Large V _O Swing)	25	50	100	-	25	100	-	kV/V
Output Voltage Swing	$R_L = 2k\Omega$	25	0	-	V+ -1.5	0	-	V+ -1.5	V

Electrical Specifications Values Apply for Each Operational Amplifier. Supply Voltage V+ = 5V, V- = 0V, Unless Otherwise Specified

Electrical Specifications	Values Apply for Each Operational Amplifier. Supply Voltage V+ = 5V, V- = 0V,
	Unless Otherwise Specified (Continued)

			ТЕМР		CA158A					
PARAMETER		TEST CONDITIONS	(⁰ C)	MIN	MIN TYP		MIN	ТҮР	MAX	UNITS
Output Current	Source	V _I + = +1V, V _I - = 0V, V+ = 15V	25	20	40	-	20	40	-	mA
	Sink	V_{I} + = 0V, V_{I} - = 1V, V+ = 15V	25	10	20	-	10	20	-	mA
		V_{I} + = 0V, V_{I} - = 1V, V_{O} = 200mV	25	12	50	-	12	50	-	μA
Short Circuit Output Curre		$R_L = 0\Omega$	25	-	40	60	-	40	60	mA
Crosstalk		f = 1 to 20kHz (Input Referred)	25	-	-120	-	-	-120	-	dB
Total Supply Current		R _L = ∞	Full	-	0.7	1.2	-	0.7	1.2	mA
		$R_L = \infty$, V+ = 30V	Full	-	1.5	3	-	1.5	3	mA

NOTES:

4. Due to the PNP input stage the direction of the input current is out of the IC. No loading change exists on the input lines because the current is essentially constant, independent of the state of the output.

5. The input signal voltage and the input common mode voltage should not be allowed to go negative by more than 0.3V. The positive limit of the common mode voltage range is V+ - 1.5V, but either or both inputs can go to +32V without damage.

6. $V_O = 1.4V$, $R_S = 0\Omega$ with V+ from 5V to 30V, and over the full input common mode voltage range (0V to V+ - 1.5V).

Electrical Specifications

Values Apply for Each Operational Amplifier. Supply Voltage V+ = 5V, V- = 0V, Unless Otherwise Specified

PARAMETER	TEST CONDITIONS	ТЕМР	СА158, СА258			CA358, LM358			CA2			
		(°C)	MIN	ТҮР	MAX	MIN	ТҮР	MAX	MIN	ТҮР	MAX	UNITS
Input Offset		25	-	2	5	-	2	7	-	2	7	mV
Voltage (Note 9)		Full	-	-	7	-	-	9	-	-	10	mV
Average Input Offset Voltage Drift	R _S = 0Ω	Full	-	7	-	-	7	-	-	7	-	μV/ ^o C
Input Common Mode Voltage Range (Note 8)	V+=30V	25	0	-	V+ - 1.5	0	-	V+ - 1.5	0	-	V+ - 1.5	V
	V+ = 30V	Full	0	-	V+ -2	0	-	V+ -2	0	-	V+ -2	V
Common Mode Rejection Ratio	DC	25	70	85	-	65	70	-	50	70	-	dB
Power Supply Rejection Ratio	DC	25	65	100	-	65	100	-	50	100	-	dB
Input Bias	lı+ or lı-	25	-	45	150	-	45	250	-	45	250	nA
Current (Note 7)	lı+ or lı-	Full	-	40	300	-	40	500	-	40	500	nA
Input Offset	lı+ - lı-	25	-	3	30	-	5	50	-	5	50	nA
Current	lı+ - lı-	Full	-	-	100	-	-	150	-	45	200	nA
Average Input Offset Cur- rent Drift		Full	-	10	-	-	10	-	-	10	-	pA/ ^o C
Large Signal Voltage Gain	$\begin{array}{l} R_L \geq 2k\Omega, V\texttt{+} \texttt{=} \texttt{15V} \\ (\text{For Large V}_O Swing) \end{array}$	25	50	100	-	25	100	-	-	100	-	kV/V
Output Voltage Swing	$R_L = 2k\Omega$	25	0	-	V+ - 1.5	0	-	V+ - 1.5	0	-	V+ - 1.5	V

Electrical Specifications	Values Apply for Each Operational Amplifier. Supply Voltage V+ = 5V, V- = 0V,
	Unless Otherwise Specified (Continued)

		TEST	темр	CA158, CA258			CA358, LM358			CA2904, LM2904			
PARAMETER		CONDITIONS	(⁰ C)	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	UNITS
Output Source Current	Source	V _I + = +1V, V _I - = 0V, V+ = 15V	25	5 20	40	-	20	40	-	20	40	-	mA
	Sink	V_{I} + = 0V, V_{I} - = 1V, V+ = 15V	25	10	20	-	10	20	-	10	20	-	mA
		V_{I} + = 0V, V_{I} - = 1V, V_{O} = 200mV	25	12	50	-	12	50	-	-	-	-	μΑ
Short Circu Output Cur	it rent (Note 2)	$R_L = 0\Omega$	25	-	40	60	-	40	60	-	40	60	mA
Crosstalk		f = 1 to 20kHz (Input Referred)	25	-	-120	-	-	-120	-	-	-120	-	dB
Total Suppl	y Current	R _L = ∞	Full	-	0.7	1.2	-	0.7	1.2	-	0.7	1.2	mA
		$R_L = \infty$, V+ = 30V	Full	-	1.5	3	-	1.5	3	-	1.5	3	mA

NOTES:

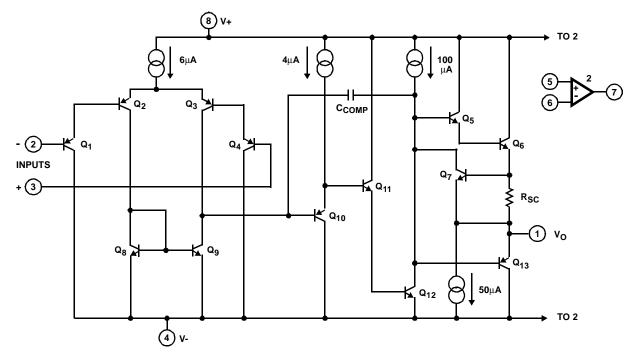
7. Due to the PNP input stage the direction of the input current is out of the IC. No loading change exists on the input lines because the current is essentially constant, independent of the state of the output.

8. The input signal voltage and the input common mode voltage should not be allowed to go negative by more than 0.3V. The positive limit of the common mode voltage range is V+ - 1.5V, but either or both inputs can go to +32V without damage.

9. $V_O = 1.4V$, $R_S = 0\Omega$ with V+ from 5V to 30V, and over the full input common mode voltage range (0V to V+ - 1.5V).

Schematic Diagram

ONE OF TWO OPERATIONAL AMPLIFIERS



Typical Performance Curves

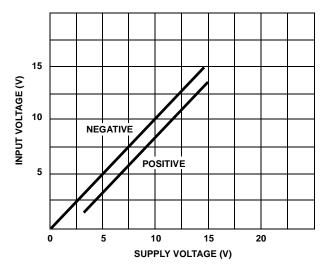


FIGURE 1. INPUT VOLTAGE RANGE vs SUPPLY VOLTAGE

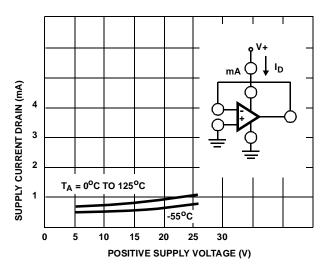
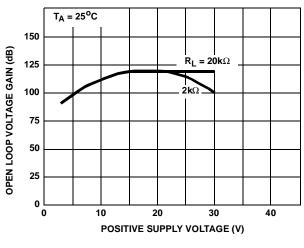


FIGURE 3. SUPPLY CURRENT DRAIN vs SUPPLY VOLTAGE





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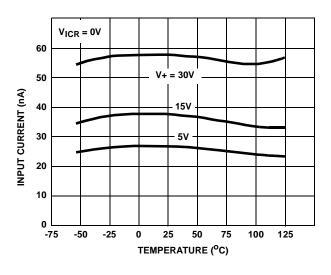


FIGURE 2. INPUT CURRENT vs AMBIENT TEMPERATURE

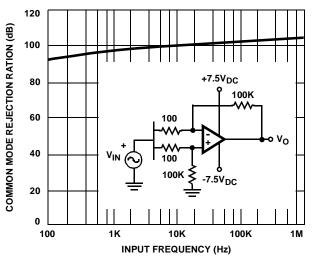


FIGURE 4. COMMON MODE REJECTION RATIO vs INPUT FREQUENCY

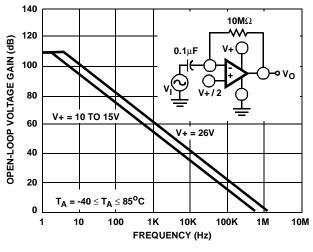
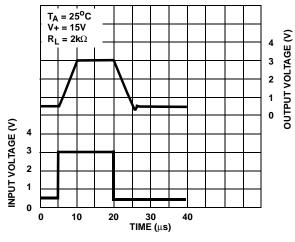


FIGURE 6. OPEN-LOOP FREQUENCY RESPONSE

Typical Performance Curves (Continued)





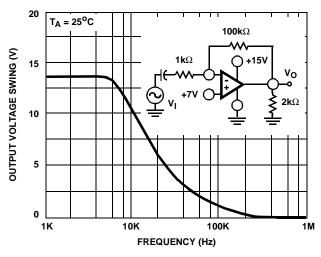


FIGURE 9. LARGE-SIGNAL FREQUENCY RESPONSE

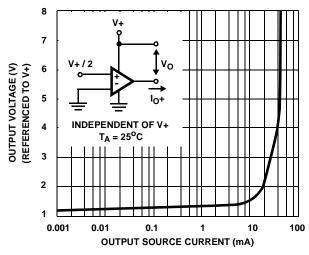


FIGURE 11. OUTPUT SOURCE CURRENT CHARACTERISTICS

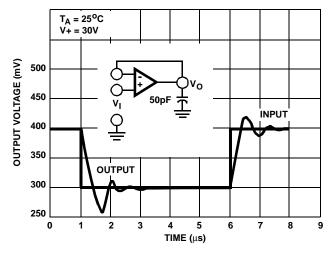


FIGURE 8. VOLTAGE FOLLOWER PULSE RESPONSE (SMALL SIGNAL)

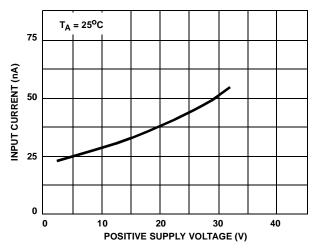


FIGURE 10. INPUT CURRENT vs SUPPLY VOLTAGE

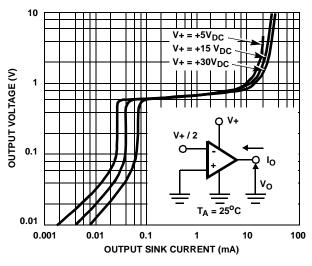
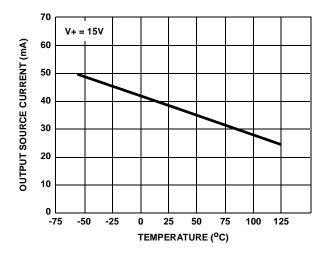


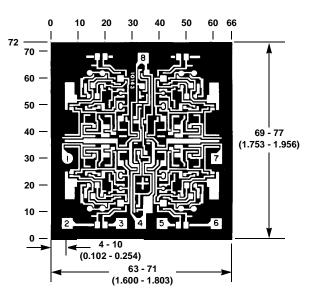
FIGURE 12. OUTPUT SINK CURRENT CHARACTERISTICS

Typical Performance Curves (Continued)





Metallization Mask Layout



Dimensions in parentheses are in millimeters and derived from the basic inch dimensions as indicated. Grid graduations are in mils (10^{-3} inch) .

The photographs and dimensions represent a chip when it is part of the wafer. When the wafer is cut into chips, the cleavage angles are 57° instead of 90° with respect to the face of the chip. Therefore, the isolated chip is actually 7mils (0.17mm) larger in both dimensions.

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